Advance Technical Information

IXTA90N20X3

X3-Class **Power MOSFET™**

N-Channel Enhancement Mode Avalanche Rated

Symbol	Test Conditions	Maximum Ratings			
V _{DSS}	$T_{J} = 25^{\circ}C$ to $175^{\circ}C$	200	V		
	$T_{_J}$ = 25°C to 175°C, $R_{_{GS}}$ = 1M Ω	200	V		
V _{gss}	Continuous	±20	V		
V _{GSM}	Transient	±30	V		
I _{D25}	$T_c = 25^{\circ}C$	90	A		
I _{DM}	$\rm T_{\rm c}$ = 25°C, Pulse Width Limited by $\rm T_{\rm _{JM}}$	220	А		
I _A	$T_c = 25^{\circ}C$	45	A		
E _{AS}	$T_c = 25^{\circ}C$	1	J		
dv/dt	$I_{_{ m S}} \leq I_{_{ m DM}}, V_{_{ m DD}} \leq V_{_{ m DSS}}, T_{_{ m J}} \leq 150^\circ C$	20	V/ns		
P _D	$T_c = 25^{\circ}C$	390	W		
T,		-55 +175	°C		
T _{JM}		175	°C		
T _{stg}		-55 +175	°C		
T	Maximum Lead Temperature for Soldering	g 300	°C		
dT/dt	Heating / Cooling rate, 175°C - 210°C	50	°C/min		
	1.6 mm (0.062in.) from Case for 10s	260	°C		
F _c	Mounting Force	1065 / 2.214.6	N/lb		
Weight		2.5	g		

Symbol (T ₁ = 25°C,	Test Conditions Unless Otherwise Specified)	Charao Min.	cteristic Typ.	/alues Max.	
BV _{DSS}	$V_{_{\mathrm{GS}}} = 0V, I_{_{\mathrm{D}}} = 250 \mu A$	200			V
V _{GS(th)}	$V_{_{DS}} = V_{_{GS}}, I_{_{D}} = 250 \mu A$	2.5		4.5	V
I _{GSS}	$V_{GS} = \pm 20V, V_{DS} = 0V$			±100	nA
I _{DSS}	$V_{_{DS}} = V_{_{DSS}}, V_{_{GS}} = 0V$ $T_{_{J}} = 125^{\circ}C$			5 100	μΑ μΑ
R _{DS(on)}	$V_{gs} = 10V, I_{D} = 0.5 \bullet I_{D25}, Note 1$			12	mΩ

TO-263

 $\mathsf{V}_{_{\mathsf{DSS}}}$

D25

 $\mathbf{R}_{\mathsf{DS(on)}}$



= 200V

= \leq

90A

 $12m\Omega$

G = Gate D = Drain S = Source Tab = Drain

Features

• International Standard Package

- Low R_{DS(ON)} and Q_G
 Avalanche Rated
- Low Package Inductance

Advantages

- High Power Density
- Easy to Mount
- Space Savings

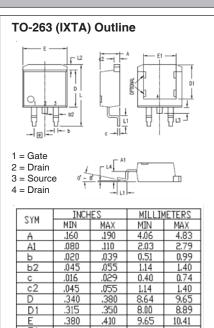
Applications

- Switch-Mode and Resonant-Mode **Power Supplies**
- DC-DC Converters
- PFC Circuits
- AC and DC Motor Drives
- Robotics and Servo Controls

LIXYS

IXTA90N20X3

Symbol (T = 25°C, l	Test Conditions Inless Otherwise Specified)	Chai Min.	aracteristic Values Typ. Max			
$\frac{\mathbf{g}_{fs}}{\mathbf{g}_{fs}}$	$V_{\rm DS} = 10V, I_{\rm D} = 0.5 \cdot I_{\rm D25}, \text{Note 1}$	60	100	S		
R _{Gi}	Gate Input Resistance		1.4	Ω		
C _{iss}			5420	pF		
C _{oss}	$V_{_{GS}} = 0V, V_{_{DS}} = 25V, f = 1MHz$		930	pF		
C _{rss}			4	pF		
	Effective Output Capacitance					
C _{o(er)}	Energy related $\int V_{GS} = 0V$		420	pF		
C _{o(tr)}	Time related $\int V_{DS}^{GS} = 0.8 \cdot V_{DSS}$		1300	pF		
t _{d(on)}	Resistive Switching Times		22	ns		
t, ($V_{gs} = 10V, V_{ps} = 0.5 \cdot V_{pss}, I_{p} = 0.5 \cdot I_{p25}$		26	ns		
t _{d(off)}	$R_{_{\rm GS}} = 5\Omega$ (External)		62	ns		
t _f	$H_{G} = 0.52$ (External)		13	ns		
Q _{g(on)}			78	nC		
Q _{gs}	$V_{gs} = 10V, V_{Ds} = 0.5 \bullet V_{Dss}, I_{D} = 0.5 \bullet I_{D25}$		23	nC		
Q _{gd}			22	nC		
R _{thJC}				0.32 °C/W		
-						



.245

.090

,040

.050

0

е

4

.<u>100</u>

6.22 2.5

14.61 2.29

1.02

1.27

0

14

IXYS REF: T 90N20X3(25-S202) 5-31-17-A

8.13

2.79

1.40

0.13

1.78

320

.625 .110

.055 .070

.005

Source-Drain Diode

Symbol					
(T _J = 25°C, L	Inless Otherwise Specified)	Min.	Тур.	Max	
I _s	$V_{gS} = 0V$			90	Α
I _{SM}	Repetitive, pulse Width Limited by $T_{_{JM}}$			360	Α
$V_{\rm SD}$	$I_{_{\rm F}} = I_{_{\rm S}}, V_{_{\rm GS}} = 0V, \text{ Note } 1$			1.4	V
t _{rr} Q _{RM} I _{RM}	I _F = 45A, -di/dt = 100A/μs V _R = 100V		124 650 10.5		ns nC A

Note 1. Pulse test, $t \le 300 \mu s$, duty cycle, $d \le 2\%$.

ADVANCE TECHNICAL INFORMATION

The product presented herein is under development. The Technical Specifications offered are derived from a subjective evaluation of the design, based upon prior knowledge and experience, and constitute a "considered reflection" of the anticipated result. IXYS reserves the right to change limits, test conditions, and dimensions without notice.

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IXYS MOSFETs and IGBTs are covered	4,835,592	4,931,844	5,049,961	5,237,481	6,162,665	6,404,065B1	6,683,344	6,727,585	7,005,734B2	7,157,338B2
by one or more of the following U.S. patents:	4,860,072	5,017,508	5,063,307	5,381,025	6,259,123B1	6,534,343	6,710,405B2	6,759,692	7,063,975B2	
	4,881,106	5,034,796	5,187,117	5,486,715	6,306,728B1	6,583,505	6,710,463	6,771,478B2	7,071,537	



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